

## BAV19WS-V, BAV20WS-V, BAV21WS-V

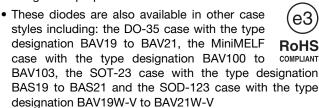
Vishay Semiconductors

# **Small Signal Switching Diodes, High Voltage**



#### **FEATURES**

- Silicon epitaxial planar diodes
- For general purpose





 Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

### **MECHANICAL DATA**

Case: SOD-323

Weight: approx. 4.3 mg
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE							
PART	TYPE DIFFERENTIATION	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS		
BAV19WS-V	V <sub>R</sub> = 100 V	BAV19WS-V-GS18 or BAV19WS-V-GS08	A8	Single diode	Tape and reel		
BAV20WS-V	V <sub>R</sub> = 150 V	BAV20WS-V-GS18 or BAV20WS-V-GS08	A9	Single diode	Tape and reel		
BAV21WS-V	V <sub>R</sub> = 200 V	BAV21WS-V-GS18 or BAV21WS-V-GS08	AA	Single diode	Tape and reel		

PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
		BAV19WS-V	V <sub>R</sub>	100	V
Continuous reverse voltage		BAV20WS-V	$V_R$	150	V
		BAV21WS-V	$V_R$	200	V
		BAV19WS-V	$V_{RRM}$	120	V
Repetitive peak reverse voltage		BAV20WS-V	$V_{RRM}$	200	V
		BAV21WS-V	$V_{RRM}$	250	V
Forward continuous current (1)			I <sub>F</sub>	250	mA
Rectified current (average) half wave recitification with resistive load (1)			I <sub>F(AV)</sub>	200	mA
Repetitive peak forward current (1)	f ≥ 50 Hz, θ = 180 °C		I <sub>FRM</sub>	625	mA
Surge forward current	t < 1 s, T <sub>J</sub> = 25 °C		I <sub>FSM</sub>	1	Α
Power dissipation (1)			P <sub>tot</sub>	200	mW

#### Note

<sup>(1)</sup> Valid provided that leads are kept at ambient temperature

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Thermal resistance junction to ambient air (1)		R <sub>thJA</sub>	650	K/W			
Junction temperature (1)		Tj	150	°C			
Storage temperature range (1)		T <sub>stg</sub>	- 65 to + 175	°C			

#### Note

<sup>(1)</sup> Valid provided that leads are kept at ambient temperature



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 100 mA		$V_{F}$			1	V
Forward voltage	I <sub>F</sub> = 200 mA		$V_{F}$			1.25	V
	V <sub>R</sub> = 100 V	BAV19WS-V	I <sub>R</sub>			100	nA
	V <sub>R</sub> = 100 V, T <sub>J</sub> = 100 °C	BAV20WS-V	I <sub>R</sub>			15	μΑ
Repetitive peak reverse voltage	V <sub>R</sub> = 150 V	BAV21WS-V	I <sub>R</sub>			100	nA
Repetitive peak reverse voltage	V <sub>R</sub> = 150 V, T <sub>J</sub> = 100 °C	BAV19WS-V	I <sub>R</sub>			15	μA
	V <sub>R</sub> = 200 V	BAV20WS-V	I <sub>R</sub>			100	nA
	V <sub>R</sub> = 200 V, T <sub>J</sub> = 100 °C	BAV21WS-V	I <sub>R</sub>			15	μA
Dynamic forward resistance	I <sub>F</sub> = 10 mA		r <sub>f</sub>		5		Ω
Diode capacitance	V <sub>R</sub> = 0, f = 1 MHz		C <sub>D</sub>		1.5		pF
Reverse recovery time	$I_F$ = 30 mA, $I_R$ = 30 mA, $I_R$ = 3 mA, $I_R$ = 100 $\Omega$		t <sub>rr</sub>			50	ns

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

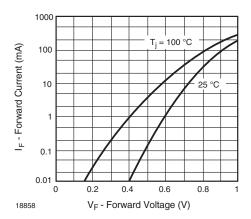


Fig. 1 - Forward Current vs. Forward Voltage

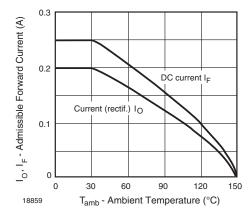


Fig. 2 - Admissible Forward Current vs. Ambient Temperature

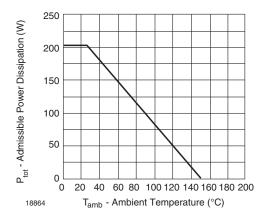


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

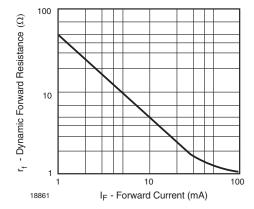


Fig. 4 - Dynamic Forward Resistance vs. Forward Current

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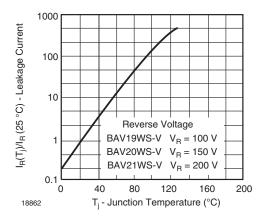


Fig. 5 - Leakage Current vs. Junction Temperature

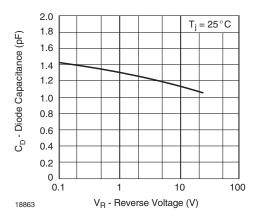
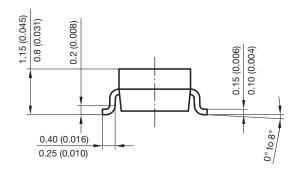
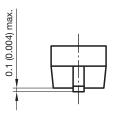
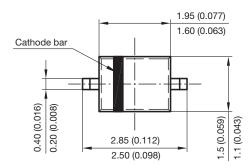


Fig. 6 - Capacitance vs. Reverse Voltage

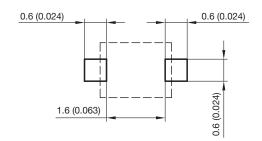
### PACKAGE DIMENSIONS in millimeters (inches): SOD-323







Foot print recommendation:



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